Sol-gel coatings for optoelectronic devices

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ABSTRACT

powders is a promising asset to use these new materials for catalytic purposes. development of nanocrystalline solar cell. c) when prepared in aerogel form, the high BET surface area of the very promising to be used in electrochromic devices, as electrodes for photoelectrochemical purpose and the and present a photoelectric effect when illuminating in the UV region (λ < 360 nm). These films are therefore insertion with 100% reversible variation of the optical transmission in the visible and near infrared range interesting properties: a) the coatings present electrochromic properties and exhibit a blue coloration under Li between 80% and 20% and have a high chemical stability (tested up to 2000 cycles) b) they are semiconductor Nb₂O₅ prepared by a sol-gel process in form of coatings and aerogels are new materials which present

I. INTRODUCTION

coatings are presently in practical use, especially for optical purposes. The sol-gel process offers today many advantages over traditional techniques for the preparation of advanced and functional coatings having optical, electronic, chemical and mechanical funcions [1]. Many sol-gel

amorphous and crystalline porous structures, a task for which the sol-gel technique appears today as mos which are presented are not exhaustive and should stimulate more thorough studies to better understand et al [2]. We then report on the preparation and physical characteristics of functional Nb₂O₅ films and discuss promising and unique. Nb₂O₅ materials with interesting properties for electrochemical and chemical applications. The original results parameters which can be used and controlled during the sol preparation and gel fabrication, allows to obtain have been mainly prepared via conventional technique; however the sol-gel process, thanks to the variety of briefly some properties of aerogels and photoelectrical behavior of Nb₂O₅ coating. Up to now these materials applications of the sol-gel techniques to make solid state electrochromic devices has been reported by Agrawal have been proposed in the last few years for the fabrication of electrochromic devices (a recent review on the In this paper, we briefly review the preparation and properties of some sol-gel coating materials which

2. SOL-GEL ELECTROCHROMIC COATINGS

current is passed through the cell, the ions stored in the counter eletrode diffuse toward the electrochromic layer are two transparent electrical conductors required for setting up a distributed electric field, an electrochromic and change its transmittance in the visible range. The original state is obtained by reversing the applied voltage layer, an ionic conductor (electrolyte) and an ion (H' or Li') storage layer (counter electrode). When a small A typical electrochromic device consists of five layers sandwiched between two glass substrates. There

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materials; all have been already obtained via sol-gel process. such as WO₃, Nb₂O₅, TiO₂, V₂O₅, TiO₂-CeO₂, MoO₃ and some mixed compounds appear to be the best Among the compositions which present an electrochromic behavior the oxides of transition metals

gradual decrease of the current indicating the occurence of an irreversible process. electrochemical stability for Li † insertion was encountered for n = 0.5; higher amount of water leads to a a the film morphology, which are essential for such application, by adequate heat treatments. The best Micrometer thick films of composition WO₃ nH₂O are easily obtained with control of the amount of water and to obtain a sol stable for several months because of the formation of a molecular oligomeric precursor oxo-chloride (WOCl,) with isopropanol is the best method of preparation as it is a cheap technique and allows with alcohols [17, 18] and hydrolysis of alkoxides [19, 15]. According to Livage [6], the reaction of tungsten tungstate [12, 13, 14], use of peroxopolytungstate acid [15, 16], reaction of tungsten chloride and oxo-chloride four sol-gel routes have been developped for the preparation of sols to deposit WO3: acidification of sodium WO₃ coatings have been the most studied electrochromic materials [3, 4, 5, 6, 7, 8, 9, 10, 11]. At leas

Using a sol prepared with a mixture of tungsten chloride (WCl₆), titanium propoxide (Ti(OPri)₄) and ethanol, Göttsche et al [20] have claimed a better electrochemical stability. However the addition of TiO₂ (10-15 mol%) reduces the number of tungsten active sites and leads to a decrease of the reversible optical

transmittance variation.

cycles for a symmetric always colored cell SnO₂/WO₃/TiO₂/WO₃/SnO₂ whose active layers have been realized against such degradation. On the other hand, Livage et al [13, 25] have claimed a lifetime longer than 40000 reaction at the TiO2/WO3 interface [22]. Coating WO3 with a thin layer of Ta2O5 [24] may offer a protection increasing number of cycles. The origin of this degradation is not known but is probably due to unwanted respectivelly, the values were comparable to those obtained with windows built with non sol-gel coatings [23] of the device during the first cycles were 60% < T < 20% at $\lambda = 550$ nm and ~ 10 s coloring and bleaching time glass/ITO/WO;(sg)/TiO;(sg)/TiO;-CeO;(sg)/ITO/glass [21, 22]. The optical transmission and time response heat treated at 120°C during 2 h. have been used by us to realized a complete sol-gel protonic smart window with the same sol-gel methods. The main drawback was the lifetime of the device whose transmission variation ΔT was gradually reduced with Using the metodology described by Livage's group [17], amorphous WO, sol-gel films 200 nm thick

0.6<x<0.67. At 500°C the coatings behave similarly to pure V₂O₃. properties strongly depend on the atomic ratio x = Ti/(V+Ti) and the calcination temperature. At 400°C for instance a two step coloration can be observed blue— green—vellow for x<0.1 and reddish-brown for coatings have been prepared by Katsumi et al [28] with sols prepared from a mixture of V and Ti alkoxides in gels have mixed electronic and protonic conductivity and Li ions insertion is reversible. Mixed V2O5-TiO2 thin isopropanol and stabilized with the addition of acetylacetone and excess acetic acid. The electrochromic route [26, 27, 9]. The nature of the material was found to mainly depend of the hydrolysis ratio H₂O/V. The instance a two step coloration can be observed blue- green-yellow for x<0.1 and reddish-brown Sol-gel electrochromic V2O, gels have been mainly synthesized by Livage's group using an alkoxide

and acetic acid as catalyst also present electrochromism under certain preparation conditions. additives used for the preparation of the sols. Ozer et al [30] using sols prepared with Ti(isoPrO)4, Ti(isoBuO). reversible color-bleaching cycles and their color can be adjusted as grey or blue depending of the chemical Amorphous TiO2 gel coatings prepared from hydrolysis and condensation of Ti(OBu), [26, 29] exhibit

electrodes. Pure CeO2 coatings shows larger storage capability[31]. CeO₂ [31, 21, 22] have high electrochemical reversibility for Li ions and have been proposed for ions storage Although they do not exhibit electrochromic properties, sol-gel coatings of CeO2 [31] and mixed TiO2

Sol-gel Nb₂O₅ films are new very promising candidate for electrochromic coatings. Very few studies have been reported on the electrochromic properties of Nb₂O₅. Reichman and Bard [32] showed the occurence of such effects in a 15µm thick coating produced on the surface of a niobium metalic disk by heating at ~500 °C for about 10 min. A coloring effect, chemically stable and with a fast kinetics (1-2s) was seen in reflexion under either H⁺ or Li⁺ insertion. Gomes et al. [33] have studied in details the protonic electrochromic properties of 20 µm thick opaque coating prepared in the same way and later Alves [34] has confirmed the possibility to insert Li ions in a 1 mm thick Nb₂O₅ ceramic prepared from commercial CBMM powder sintered at 800°C.

The first attempt to fabricate sol-gel Nb₂O₅ for electrochemical purpose has been reported by Lee and Crayston [35] who have spin coated ITO coated glass electrode with a mixture of NbCl₅ dissolved in EtOH. Hydrolysis and gelation were completed in 1 mol/dm³ H₂SO₄ solution. After drying at room temperature the result was a 5-10 μm thick film with substantial cracking (10 μm islands) and peeling due to important shrinkage. Cyclic voltammograms in LiClO₄-MeCN electrolyte showed a blue coloration with a fast coloration (- 6s) and bleaching (-3s) kinetics and a 6 cm²/C coloring efficiency. However the durability of the electrochromic response was only a few cycles. The quality of the film has been slightly improved by adding a trialkoxysilane (Glymo) to the precursor sol in order to obtain a Nb-Si Ormocer.

In our laboratory, Nb_2O_3 sols have been prepared using an alkoxide route (figure 1a). Pentabutoxide of niobium (Nb(OBu_n)₅) was first synthetized following the process described by Bradley et al [36] by dissolving niobium chloride (NbCl₅) from CBMM-Brazil in butanol and then mixed with sodium butoxide (Na(OBu_n)) under reflux. During the process a strong exothermic reaction occurs leading to the formation of Nb(OBu_n)₅ and NaCl. The last compound was then separated by centrifugation to obtain a yellow and transparent precursor sol. The final sol was prepared by mixing this precursor with glacial acetic acid (CH₃COOH) with molar ratio 1:2 resulting in a sol stable at room temperature for several month. [37]. The coatings have been deposited by dip coating technique on Donnelly or Asahi Glass ITO coated glass at a withdrawal speed of 12 cm/min, dried at room temperature during 5 min and then densified at 400° C during 15 min. They have typically a thickness of ≈ 80 nm. The process has been repeated three times to obtain a 250 nm thick film; the final coating has been finally heat treated in O₂ atmosphere between 400 and 600°C. [21, 37]. Figure 1b shows a block diagram of this procedure.

Figure 2 shows a typical SEM micrograph and EDX scan of Nb (taken at the location of the line shown on the micrograph) of a three layers Nb₂O₅ film (250 nm thick) obtained according to the above procedures with a heat treatment at 560°C in O₂ atmosphere during 2 h. The picture shows very good homogeneity of the Nb atoms and excellent microstructure of the surface with no visible cracks and defects.

X-ray diffractograms of xerogels obtained with the same sol have been obtained with a Rigaku model RU200B instrument with a K α Cu radiation. Figure 3 shows that the gels heat treated up to 500 0 C are amorphous. At 560 0 C the material is crystalline but the lines are poorly defined. Their position and intensity are compatible with the so-called TT phase as can be seen by comparison with the top part of the figure[38,39]. The width of the principal lines somewhat sharpens at 600 0 C but the overall shape of the spectrum does not change. No trace of other phases (T,M,H) has been observed. According to Ko [38], the TT phase is not strictly a niobium pentoxide as some oxygen atoms are replaced by monovalent species such as X = OH; CI; vacancies etc. and Nb atoms occupy separated but closely-spaced equivalent sites or intermediate positions between them; the compound should be better denoted Nb₁₆O₃₈X₄ or Nb₂(OX)_{5:n}. DSC and DTA measurements (TA 9010 Instrument) made at 2 0 C/min in a O₂ flux confirm the presence of a small crystallization peak at ~ 580 $^{\circ}$ C (formation of the TT-phase) followed by an intense peak with maximum at

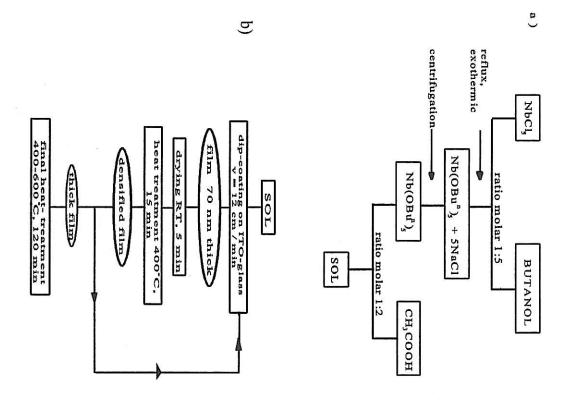


Fig. 1 Block diagram of a) Nb₂O₅ sol preparation and b) Nb₂O₅ film preparation.



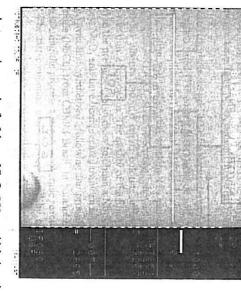


Fig. 2 Scanning electron micrograph of a 3 layers Nb₂O₅ 250 nm thick deposited on glass/ITO (Donnelly) substrate heat treated at 560°C during 2h in O₂ atmosphere and EDX line scan of Nb.

630°C (probably due to the transformation TT-T).

Figure 4 presents typical voltammograms measured at speed varying from 2 to 200 mV/s between +2.0 and -1.8 V(vs Ag/AgCl reference) for a 3 layers Nb₂O₅ coating deposited on ITO coated glass (Asahi Glass) and sintered 2 h at 560°C in oxygen. The measurements have been performed with a Solartron 1226 electrochemical interface and a cell consisting of three electrodes: a Pt foil (1 cm²) as counter electrode, an Ag/AgCl as a quase-reference electrode and the "Nb₂O₅" film as working electrode (working area 0.3 cm²). The electrolyte was LiClO₄ dissolved in propylene carbonate with concentration 0.1M and has been previously purged with dry N₂ gas. All the electrochemical measurements have been done in a dry box containing N₂ atmosphere with less than 100 ppm H₂O. We must first mention that the voltammograms could not be registered at potential value lower than -2.0 V. Below this value the cathodic current increases very rapidly, the coating turns black and is permanently damaged. Electrochemical measurements made with uncoated but heat treated ITO substrates shows that this effect is due to the reduction of this material. Within the safe range of -1.8 to 2.0 V, two different regimes can be observed.

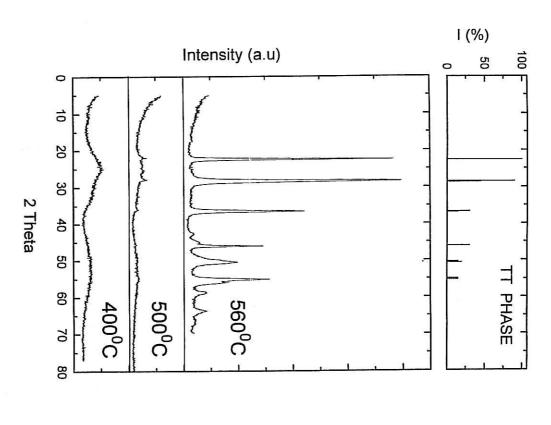


Fig. 3 Lower part: X-ray diffraction of $\mathrm{Nb_2O_5}$ xerogels heat treated at 400, 500, 560°C during 2h in $\mathrm{O_2}$ atmosphere. The top part shows the position of the principal peaks of the TT phase

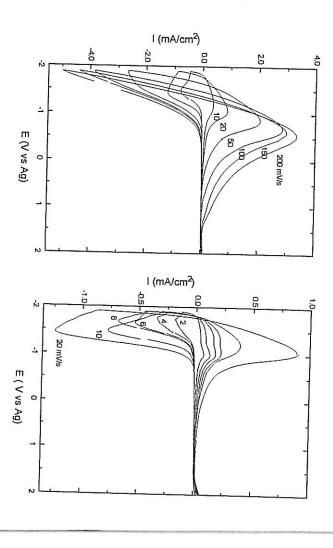


Fig. 4 Voltammograms of a 250 nm thick Nb₂O₅ coating deposited on a glass/ITO (Asahi Glass) substrate and heat treated at 560 °C during 2h in O₂ atmosphere. Electrolyte N₂ purged 0.1M LiClO₄/PC; reference Ag/AgCl, potential scan +2 V to -1.8 V a) scan rates 2,4,6,8,10,20 mV/s and b) scan rates 10,20,50,100,150 and 200 mV/s.

At low speed (v < 10 mV/s) the curves are rather complex and appear as a superposition of at least two insertion phenomena, one into the niobate coating and the other into the ITO coating to which belong the cathodic and anodic waves observed at -1.7 and -1V respectively (figure 4a). BET measurements (not shown here) indicate that xerogels have still at 560 °C a relatively high porosity and as the charge inserted, Q_C , is high and constant ($Q_C \approx 20$ mC/cm²), as shown in figure 5 , it seems that, at these low scan rates, the Li⁺ ions have time to reach the electronic coating. On the other hand as shown in the same figure , the cycles are not reversible: the total charge extracted, Q_{A_D} is smaller than the total charge inserted and consequently the ratio Q_A/Q_C is smaller than 1. The color of the coating after Li insertion is blue-black and after bleaching the system remains sligthly colored.

For scan rate higher than 10 mV/s the voltammograms are totally different (figure 4b). At lower speed the Li insertion peak is clearly visible, but shifts rapidly to lower and out of range potentials when the speed is increased. The extraction peak can be observed in the whole scan range and also shifts but to higher potential values. Although the value of the charge inserted or extracted diminish with the speed, their ratio Q_c/Q_A remains now constant and approximately 1 (figure 5) indicating that the process is fully reversible in this speed range.

The variation of the maximum intensity of the cathodic and anodic currents with the scan rate is

The variation of the maximum intensity of the cathodic and anodic currents with the scan rate is practically impossible to measure as at low speed it is necessary to make a careful deconvolution of the insertion processes and at high speed, the maximum of the insertion peak is not observed in the safe potential range used and the values of I_{max} of the extraction peak shoud be measured from the base line of the cathodic part at low negative potential, a task which is impossible to realize without a better knowledge of the chemical processes occurring at the electrode. Therefore it is not possible to argue if the process is limited by the Li diffusion or is due to a superficial phenomenon. Measurements are underway with coatings deposited on metallic substrate in order to avoid the ITO reduction occurring at ~ 2.0 V and extend the potential range to lower values.

In this speed range and after Li insertion the color of the coating is deep blue. Figure 6 shows the optical transmission spectrum measured in situ with a Cary 17 spectrophotometer in the range 300 to 1100 mm at different applied potentials either during the insertion or the extraction process. A small hysteresis is observed but the good superposition of the curves in the bleached state at + 2.0 V shows that the system is totally reversible.

Figure 7 shows the result of a chronoamperometry where the current was registered during the application of a square pulse of +2.0 to -1.8 V. The insertion process has a time response of about 10 s while the extraction process is faster, about 4 s.

For coatings deposited either on Asahi Glass or Donnelly ITO and heat treated in O_2 atmosphere the charge is constant since the first cycles and the temporal behavior tested up to 2000 cycles shows an excellent chemical stability (figure 8). When the coatings are amorphous (i.e. for heat treatment at $T \le 500$ °C), the inserted (or extracted) charge first increases up to about 500 cycles and then decreases; this behavior suggests some structural evolution of the amorphous oxide network. The shape of the voltammograms measured at 50 mV/s are similar to that shown in figure 4b but the color of the layer is brown and the amount of charge inserted is smaller. When the coatings are heat treated in air instead of O_2 at temperature between 400 and 560 °C, we found that the amount of charge slightly decreases with the number of cycles for both type of substrates. It is also possible to insert proton in these coatings. The cycles are also reversible but the lifetime of the coatings is short and does not exceed a few cycles We believe that the bad performance is due to corrosion problems as it is with WO₃ coating.

In conclusion we can state that "niobate" coating can now be prepared by the sol-gel process with excellent optical quality without cracks and good homogeneity. These coatings show reversible electrochromic properties when measured at scan rate higher than 10 mV/s and exhibit a deep blue coloration similar to that of WO₃ coating. The variation of the optical transmission is high for a 250 nm thick layer and the kinetics of the

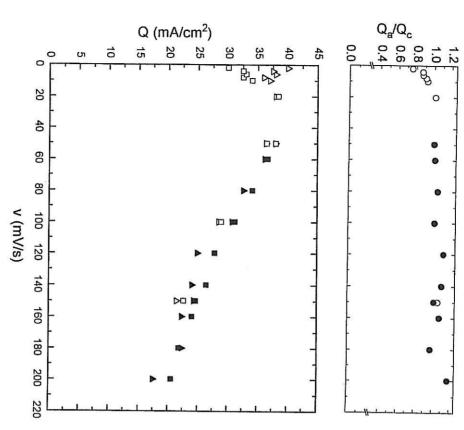
Fig. 5 Lower part : Inserted charge Q_c (\P , \square)and extracted charge (\blacktriangle , Δ) integrated from the

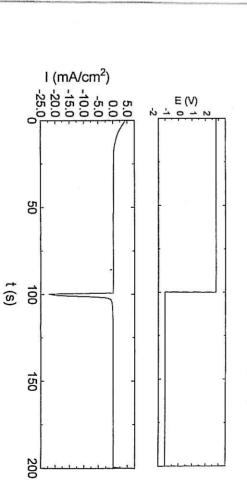
voltammograms obtained with two films prepared in the same conditions versus scan rate. Upper

part : ratio Q_C/Q_A versus scan rate.



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(same electrochemical conditions as figure 4). Fig. 7 Chronoamperometry of Nb₂O₃ coating heat treated at 560 °C during 2h in O₂ atmosphere



T (%)

-1,3 V

-1,1 V

60

80

40

20

200

400

600

800

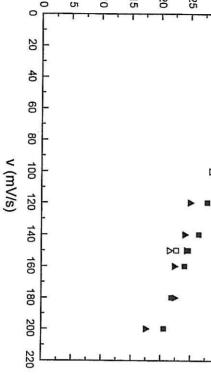
1000

1200

-1,8 V

 λ (nm)

100



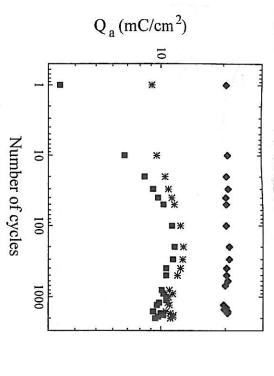


Fig. 8 Time dependence of the charge inserted (or extracted) as a function of the number of voltammetry cycles (+2V to - 1.8 V) measured at a scan rate of 50 mV/s. The coatings have been heat treated for 2h in O_2 atmosphere at (\spadesuit) 560 °C (crystalline), (\blacksquare)500 °C (amorphous) and (\bullet) 400 °C (amorphous).

insertion and extraction processes is quite adequate to use these coatings as electrochromic layer to built smart windows or mirrors, a research which is presently underway in our laboratory.

3. SOL-GEL NB₂O₅ AS CATALYST

Niobate materials in a wide variety of forms have been recently found active for many catalytic reactions [38]. When incorporated to V₂O₅, the most popular catalyst for decomposition of NO in the industrial stack gas to prevent air pollution, Nb₂O₅ has been shown to have a *promoting* effect.

Remarkable *support* effect was reported on Rh catalyst for activity and selectivity toward higher cations in Co+H₂ reaction. Nb₂O₃ deposited on Ni shows much higher conversion then Ni/Al₂O₃ catalyst for CO hydrogenation and Pd and Co/Nb₂O₃ catalysts are for instance more interesting then Al₂O₃ for the synthesis of methylisobutyl ketone from acetone. However the most interesting properties of Nb₂O₃ arise from its high acidic behavior when hydrated. When calcined at 100-300°C, Nb₂O₃.nH₂O exhibits a high acid strenght (H₆ = -5,6) corresponding to the acid strenght of 70% H₂SO₄; this material is expected to show high and stable catalytic

activity for acid catalyzed reactions in which water molecules participate or are liberated such as the hydration of ethylene into ethylalcohol for instance.

For these applications, it is evident that the surface area of the materials should be as high a possible. The material, as produced in powder form by CBMM (Brazil) has a typical value $S \approx 75-100 \text{ m}^2/\text{g}$. The preparation of highly porous materials using supercritical drying of gels, a technique which has mainly been applied to the preparation of silica aerogel[40], is one of the method which can be used to obtain materials with higher surface area.

The preparation of sol to obtain Nb₂O₃ aerogel, has been slightly modified. The niobium alkoxide (NbOC₄H₉)₅, prepared as above, was first hydrolized at room temperature with bidestilled water and HNO₃ under mechanical stirring using molar ratio H₂O/Nb = 10 and HNO₃/Nb = 0.8. The sol was let to gel during ?h. Nb₂O₃ aerogels have been then obtained by supercritical drying using CO₂ as extracting agent at 60 atm and a critical temperature of 250°C. The CO₂ flux was adjusted to 6 l/h and the time of extraction was 1 h. Calcination of the aerogel has been performed in air.

The values of the BET surface area of aerogel heat treated at 300°C during 12 h are almost 2,5 times larger than the commercial (CBMM-AD638) product and remain practically constant up to 500°C while for the CBMM product the value has been already reduced to one half. More interesting is the fact that the ratio of the surface area S(aerogel) / S(CBMM) is about 2 at 300°C, increases to 4 at 500°C and remains 4 up to 700°C although both compounds suffer a drastic decrease of their S values. The supercritical drying process appears therefore to delay considerably the densification process and allows to maintain a more open structure.

Modifications have also been observed on the crystalline structure and the morphology of the materials. At 500°C the commercial product has a mixed crystalline structure of type T and TT [38] while the aerogel is still practically amorphous. At 700°C both structures are crystalline. The morphology of the sample are also quite different. Scanning electron studies of different amplification indicate that the size of the colloidal particles which form the aerogel remains practically the same up to 700°C while in the commercial product the particles shows a definite tendency to grow into larger particles[41].

4. NB,O, AS PHOTOELECTRICAL COATING

Recently a new photovoltaic solar cell concept has been developped by Graetzel et al.[42]. The device is based on the use of small (\sim 20 nm) coloidal semiconductor particles of TiO₂ prepared by a sol-gel process and sintered at low temperature and whose superficie has been sensitized by a monolayer of transition metal complex in order to shift the absorption spectrum of TiO₂ (λ < 380 nm) toward the visible solar range. Contrary to conventional semiconductor cells, the nanocrystaline device separates the function of light absorption (charge creation) and charge transport. The light is first absorbed by the sensitizer whose absorption spectral range can be adapted to the solar spectral range by a careful choice of its composition. The excited eletrons are then transfered to the conduction band of the TiO₂ where they rapidly diffuse through the thin coating (\sim 2 μ m) and are collected by a conducting electrode. The cycle is then closed by returning the electrons to a counter electrode and through an adequate electrolyte which allows the regeneration of the sensitizer cations by electronic transfer. In such device, the TiO₂ coating has therefore two functions and act as a support for the sensitizing molecules and for the eletronic charge transport.

Several other oxides present semiconducting properties including BaTiO₃, WO₃, Nb₂O₅, SrTiO₂, KTaO₃, Ta₂O₅, etc. Nb₂O₅ can be obtained in form of small colloidal particles. The material has a band gap slightly larger than TiO₂ and the flat band potential vs SHE is 0V [43], slightly smaller than TiO₂ (0.2V).

The fabrication of 250 nm thick Nb₂O₅ coating and the electrochemical test have been realized as described in section 2. However UV light from a 100 W Xe lamp was coupled to a Bausch and Lomb UV-

of solar cell similar to thos developed by Graetzel et al. [44] of the electrochemical cell. Preliminary measurements show that niobate coatings present a photoelectric effect however less intense that TiO_2 coatings and may be of interest to substitute these coatings for the realization Visible high intensity monochromator and focussed on the sample through a quartz window adapted on the side

to be used for photoelectrochemical applications such as the realization of nanocrystalline solar cells. material presents a photoelectric effect when illuminating in the UV region. They are consequently promising promising for catalytic purposes. Small colloidal particles have also been obtained and it was shown that this aerogels can be prepared with a higher surface area than the commercial CBMM product, a result very is reversible for scan rate higher than 10 mV/s. Therefore these new coatings are very promising to substitute atmosphere present interesting electrochromic properties and turn blue under Litions insertion. The process of coating with excellent optical quality, xerogel or aerogel. The coatings heat treated at 560 °C in O2 WO₃ coatings for the realization of smart windows and mirrors. Preliminary measurements also indicate that We have shown that it is possible to prepare Nb2O5 materials by a sol-gel process either in the form

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